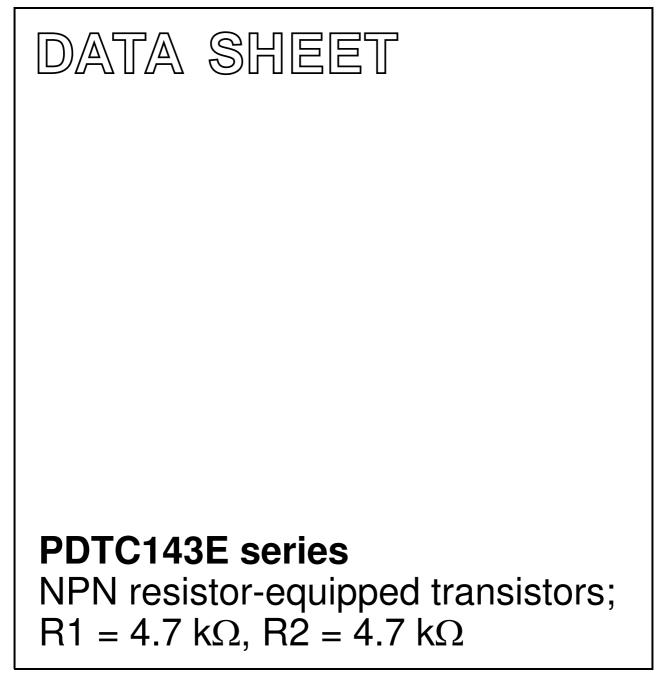
DISCRETE SEMICONDUCTORS



Product data sheet Supersedes data of 2004 Mar 18 2004 Aug 05



PDTC143E series

FEATURES

- · Built-in bias resistors
- Simplified circuit design
- Reduction of component count
- Reduced pick and place costs.

APPLICATIONS

- General purpose switching and amplification
- Inverter and interface circuits
- Circuit driver.

PRODUCT OVERVIEW

QUICK REFERENCE DATA

SYMBOL	PARAMETER	TYP.	MAX.	UNIT
V _{CEO}	collector-emitter voltage	-	50	V
lo	output current (DC)	-	100	mA
R1	bias resistor	4.7	-	kΩ
R2	bias resistor	4.7	-	kΩ

DESCRIPTION

NPN resistor-equipped transistor (see "Simplified outline, symbol and pinning" for package details).

TYPE NUMBER	PACKAGE			PNP COMPLEMENT	
	PHILIPS	EIAJ			
PDTC143EE	SOT416	SC-75	02	PDTA143EE	
PDTC143EEF	SOT490	SC-89	51	PDTA143EEF	
PDTC143EK	SOT346	SC-59	02	PDTA143EK	
PDTC143EM	SOT883	SC-101	E1	PDTA143EM	
PDTC143ES	SOT54 (TO-92)	SC-43	TC143E	PDTA143ES	
PDTC143ET	SOT23	_	*02	PDTA143ET	
PDTC143EU	SOT323	SC-70	*02	PDTA143EU	

Note

- 1. * = p: Made in Hong Kong.
 - * = t: Made in Malaysia.
 - * = W: Made in China.

PDTC143E series

SIMPLIFIED OUTLINE, SYMBOL AND PINNING

	SIMPLIFIED OUTLINE AND SYMBOL		PINNING		
TYPE NUMBER			DESCRIPTION		
PDTC143ES	$\begin{bmatrix} 1 \\ 0 \\ 0 \\ 0 \\ 0 \\ 0 \\ 0 \\ 0 \\ 0 \\ 0 \\$	1 2 3	base collector emitter		
PDTC143EE PDTC143EEF PDTC143EK PDTC143ET PDTC143EU	3 1 3 1 2 1 Top view MDB269	1 2 3	base emitter collector		
PDTC143EM	2 1 bottom view MHC506	1 2 3	base emitter collector		

PDTC143E series

ORDERING INFORMATION

TYPE NUMBER	PACKAGE			
ITPE NUMBER	NAME	DESCRIPTION	VERSION	
PDTC143EE	_	plastic surface mounted package; 3 leads	SOT416	
PDTC143EEF	_	 plastic surface mounted package; 3 leads 		
PDTC143EK	 plastic surface mounted package; 3 leads SC 		SOT346	
PDTC143EM	_	$- \qquad \ \ \ \ \ \ \ \ \ \ \ \ \$		
PDTC143ES	 plastic single-ended leaded (through hole) package; 3 leads 		SOT54	
PDTC143ET	_	plastic surface mounted package; 3 leads	SOT23	
PDTC143EU	 plastic surface mounted package; 3 leads SOT 		SOT323	

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	-	50	V
V _{CEO}	collector-emitter voltage	open base	-	50	V
V _{EBO}	emitter-base voltage	open collector	-	10	V
VI	input voltage				
	positive		_	+30	V
	negative		-	-10	V
I _O	output current (DC)		-	100	mA
I _{CM}	peak collector current		—	100	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$			
	SOT54	note 1	_	500	mW
	SOT23	note 1	_	250	mW
	SOT346	note 1	_	250	mW
	SOT323	note 1	_	200	mW
	SOT416	note 1	_	150	mW
	SOT883	notes 2 and 3	_	250	mW
	SOT490	notes 1 and 2	_	250	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T _{amb}	operating ambient temperature		-65	+150	°C

Notes

- 1. Refer to standard mounting conditions.
- 2. Reflow soldering is the only recommended soldering method.
- 3. Refer to SOT883 standard mounting conditions; FR4 with 60 μ m copper strip line.

PDTC143E series

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th(j-a)}	thermal resistance from junction to ambient	in free air		
	SOT54	note 1	250	K/W
	SOT23	note 1	500	K/W
	SOT346	note 1	500	K/W
	SOT323	note 1	625	K/W
	SOT416	note 1	833	K/W
	SOT883	notes 2 and 3	500	K/W
	SOT490	notes 1 and 2	500	K/W

Notes

- 1. Refer to standard mounting conditions.
- 2. Reflow soldering is the only recommended soldering method.
- 3. Refer to SOT883 standard mounting conditions; FR4 with 60 μ m copper strip line.

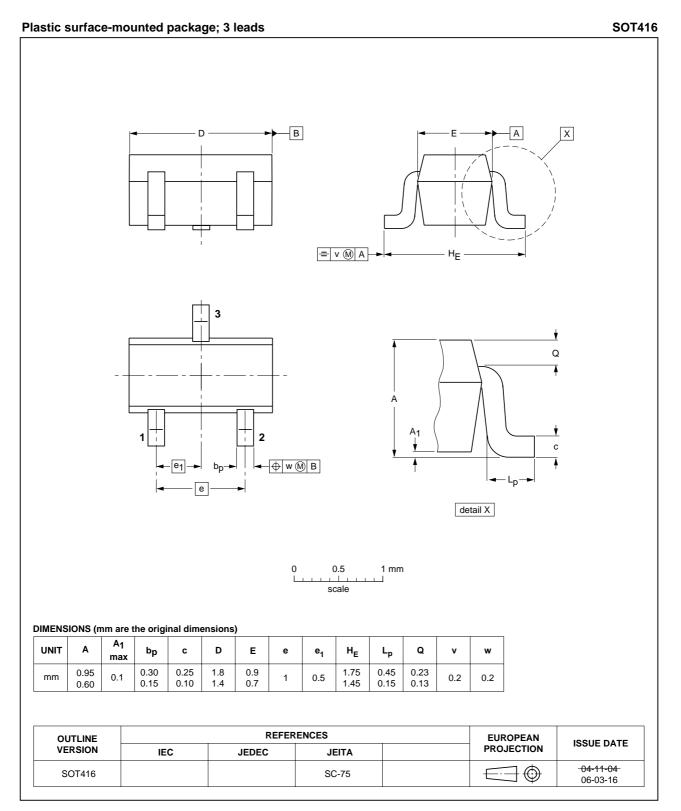
CHARACTERISTICS

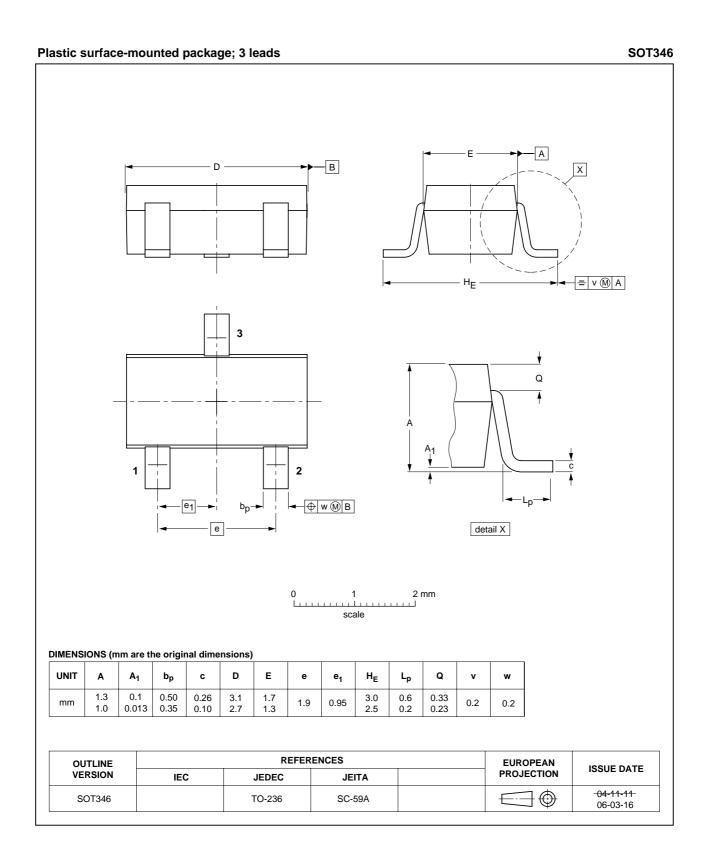
 T_{amb} = 25 $^\circ C$ unless otherwise specified.

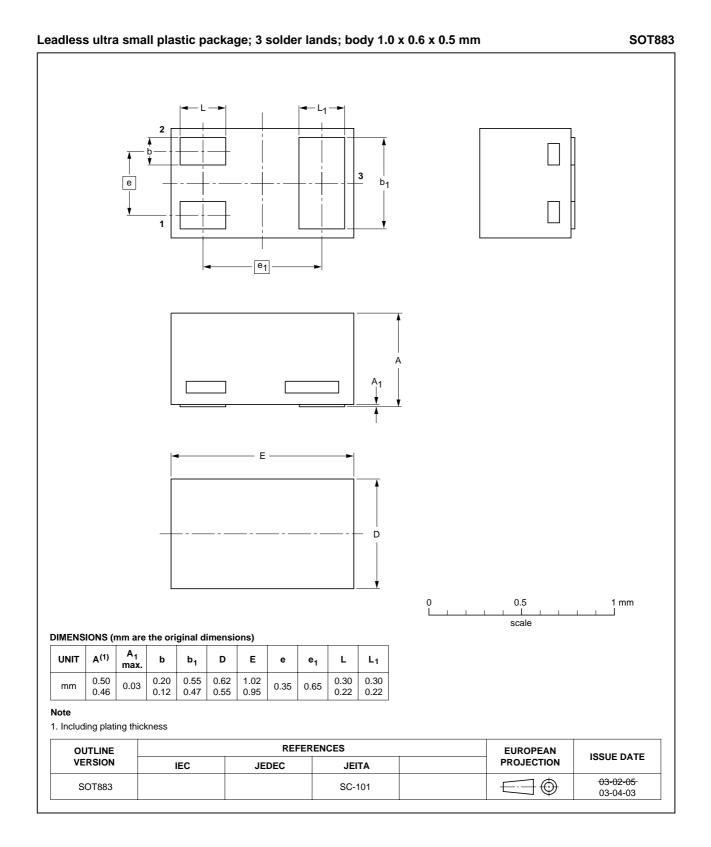
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CBO}	collector-base cut-off current	$V_{CB} = 50 \text{ V}; \text{ I}_{E} = 0 \text{ A}$	-	_	100	nA
I _{CEO}	collector-emitter cut-off current	$V_{CE} = 30 \text{ V}; I_B = 0 \text{ A}$	_	-	1	μA
		$V_{CE} = 30 \text{ V}; \text{ I}_{B} = 0 \text{ A}; \text{ T}_{j} = 150 ^{\circ}\text{C}$	-	_	50	μA
I _{EBO}	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_{C} = 0 \text{ A}$	-	-	900	μA
h _{FE}	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 10 \text{ mA}$	30	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_{C} = 10 \text{ mA}; I_{B} = 0.5 \text{ mA}$	-	_	150	mV
V _{i(off)}	input-off voltage	$I_{C} = 100 \ \mu A; V_{CE} = 5 \ V$	-	1.1	0.5	V
V _{i(on)}	input-on voltage	$I_{C} = 20 \text{ mA}; V_{CE} = 0.3 \text{ V}$	2.5	1.9	-	V
R1	input resistor		3.3	4.7	6.1	kΩ
<u>R2</u> R1	resistor ratio		0.8	1	1.2	
C _c	collector capacitance	$\begin{split} I_E = i_e = 0 \text{ A}; V_{CB} = 10 \text{ V}; \\ f = 1 \text{ MHz} \end{split}$	-	-	2.5	pF

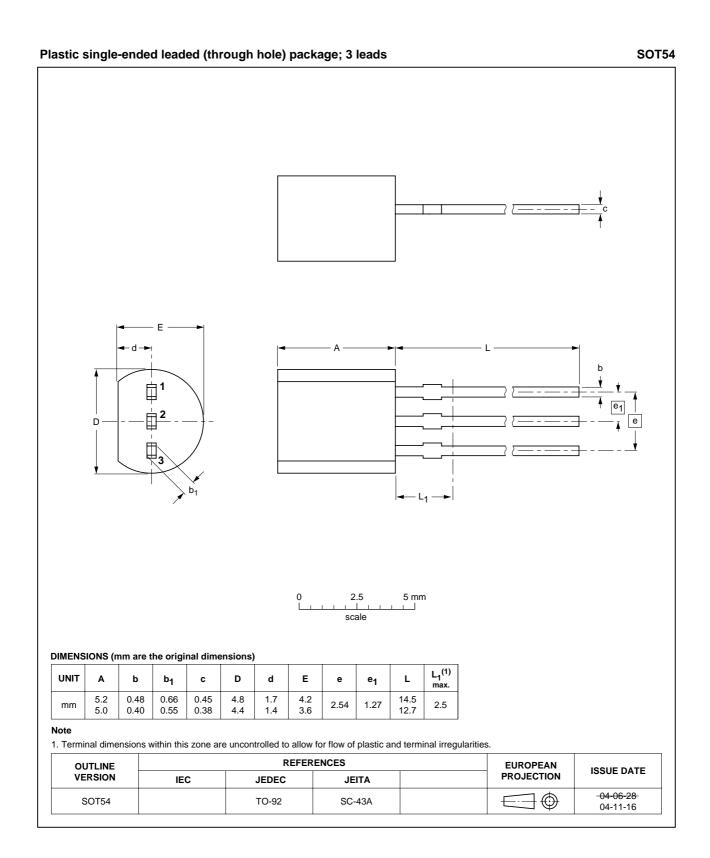
PDTC143E series

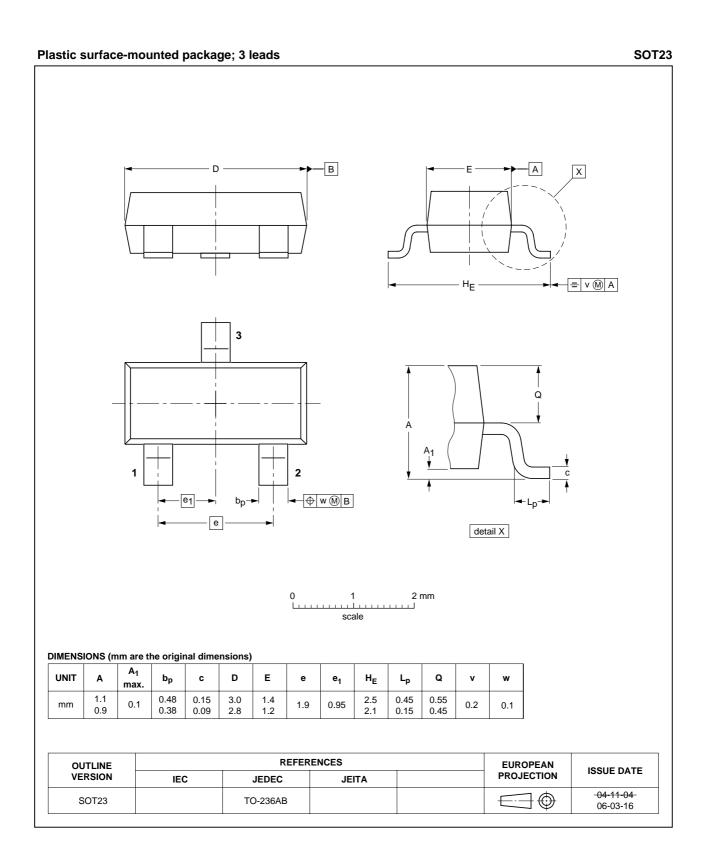
PACKAGE OUTLINES

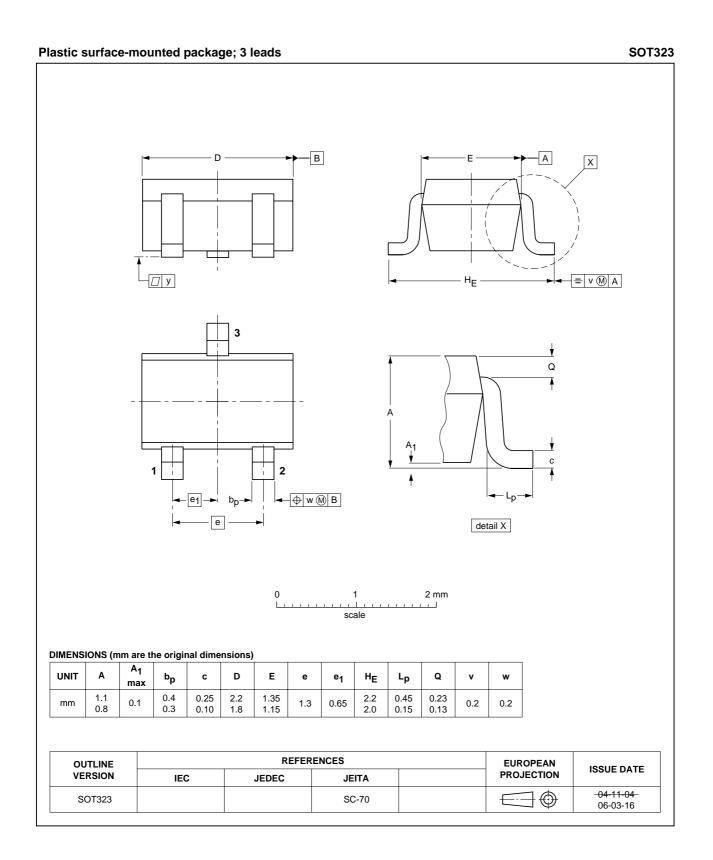


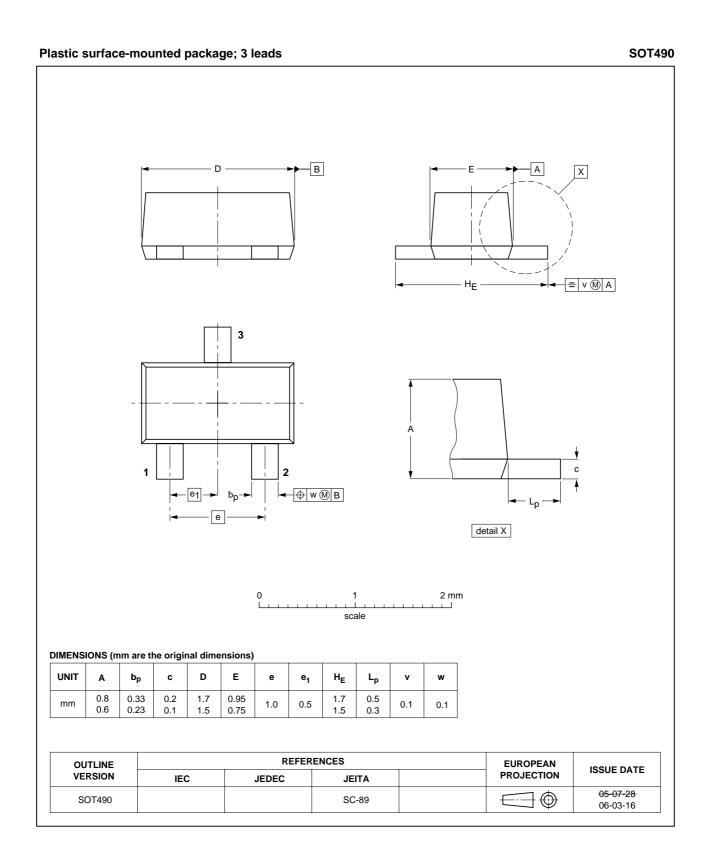












PDTC143E series

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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Customer notification

This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content, except for package outline drawings which were updated to the latest version.

Contact information

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